

Current Sensor

Current Sense Amplifier

BD14210G-LA

General Description

The BD14210G-LA current sense amplifier.

This is the product guarantees long time support in Industrial market.

This device operates from a single 2.7 V to 5.5 V power supply.

It has wide common mode voltage range from -0.2 V to +26 V, outputs analog voltage. The gain is 20 V/V.

The matched gain resistor minimizes gain error and realizes low offset voltage.

The input bias current is 1 μA (Typ) at typical condition. There is no need to adjust the gain error.

Features

- Long Time Support Product for Industrial Applications.
- Wide Common Mode Voltage Range
- High Accuracy
- Low Offset Voltage
- Low Input Bias Current

Key Specifications

VDD Voltage Range: 2.7 V to 5.5 V
Quiescent Current: 170 μA (Typ)
Common Mode Voltage Range: -0.2 V to +26 V
Gain: 20 V/V (Typ)
Gain Accuracy: ±1.0 % (Max)
Operating Temperature Range: -40 °C to +125 °C

Package SSOP6

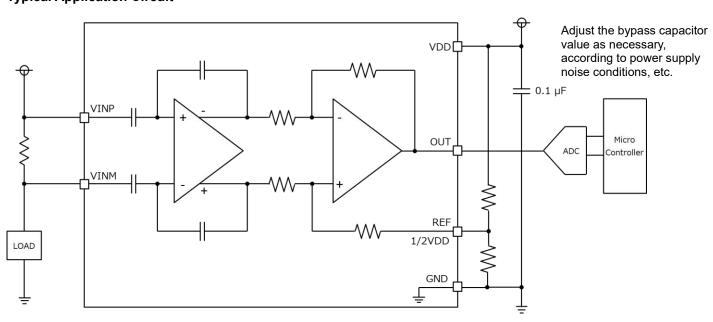
W (Typ) x D (Typ) x H (Max) 2.9 mm x 2.8 mm x 1.25 mm



Applications

- Industrial Equipment
- Telecom Equipment
- Over Current Detection

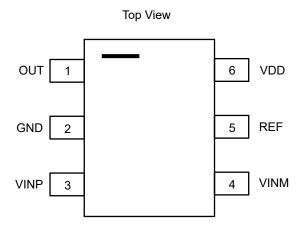
Typical Application Circuit



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Pin Descriptions



Pin Configurations

Configuration	3				
Pin No.	Pin Name	Function			
1	OUT	Current detection output			
2	GND	Ground			
3	VINP	Input of supply side of shunt resister			
4	VINM	Input of load side of shunt resister			
5	REF	Reference input			
6	VDD	Power supply ^(Note 1)			

(Note 1) Dispose a bypass capacitor between VDD and GND.

Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Rating	Unit
Power Supply Voltage	V_{DD}	7.0	V
Common Mode Voltage	V _{CM}	-0.2 to +26	V
Input Voltage	VIN	-0.3 to V _{DD} +0.3	V
Storage Temperature Range	Tstg	-55 to +150	°C
Maximum Junction Temperature	Tjmax	150	°C

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

Thermal Resistance (Note 2)

Parameter		Thermal Res	1.1	
		1s ^(Note 4)	2s2p ^(Note 5)	Unit
SSOP6				
Junction to Ambient	θја	376.5	185.4	°C/W
Junction to Top Characterization Parameter ^(Note 3)	Ψ_{JT}	40	30	°C/W

(Note 2) Based on JESD51-2A (Still-Air).

(Note 3) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package. (Note 4) Using a PCB board based on JESD51-3. (Note 5) Using a PCB board based on JESD51-7.

(Note 3) Using a FCB board based of	JII JESDS 1-7.					
Layer Number of Measurement Board	Material	Board Size				
Single	FR-4	114.3 mm x 76.2 mm x 1.57 mmt				
Тор						
Copper Pattern	Thickness					
Footprints and Traces	70 µm					
Layer Number of Measurement Board	Material	Board Size				
4 Layers	FR-4	114.3 mm x 76.2 mm	x 1.6 mmt			
Тор		2 Internal Layers		Bottom		
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness	
Footprints and Traces	70 µm	74.2 mm x 74.2 mm	35 µm	74.2 mm x 74.2 mm	70 µm	

Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit	Condition
Power Supply Voltage	V_{DD}	2.7	-	5.5	V	
Common Mode Voltage	Vсм	-0.2	-	+26	V	VINP, VINM
Operating Temperature	Topr	-40	+25	+125	°C	

Electrical Characteristics

(Unless otherwise specified V_{DD} = 5 V, V_{REF} = 1/2 x V_{DD} , V_{CM} = 12 V, V_{SENSE} = (V_{VINP} - V_{VINM}), Ta = 25 °C)

	- 55	,		, ,	CHOL (- 11111 - 111111/, /
Parameter	Symbol	Min	Тур	Max	Unit	Condition
Power Supply	1					
Quiescent Current	I _{DD}	-	170	280	μA	V _{SENSE} = 0 mV
Current Sense Amplifier						
Offset Voltage	Vos	-	-	±0.6	mV	RTI ^(Note 6) , V _{SENSE} = 0 mV
Gain	Gain	-	20	-	V/V	
Gain Accuracy	GERR	-	-	±1.0	%	V _{OUT} = 0.5 V to V _{DD} -0.5 V Ta = -40 °C to +125 °C
Nonlinearity Error	Lin	-	±0.01	-	%	$V_{OUT} = 0.5 \text{ V to } V_{DD} - 0.5 \text{ V}$
Input Bias Current	I _{VINM}	-	1.0	-	μA	V _{SENSE} = 0 mV Ta = -40 °C to +125 °C
High-level Output Voltage	Vоит_н	V _{DD} - 0.02	-	-	V	OUT, RL = 10 KΩ pulldown
Low-level Output Voltage	V _{OUT_L}	-	-	GND + 0.05	V	OUT, RL = 10 KΩ pullup

(Note 6) RTI = Referred To Input

Typical Performance Curves

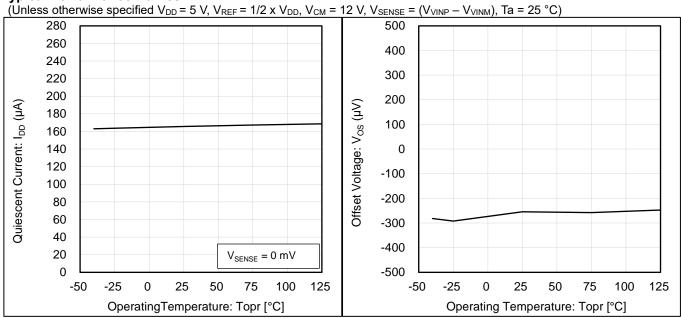


Figure 1. Quiescent Current vs Operating Temperature

Figure 2. Offset Voltage vs Operating Temperature

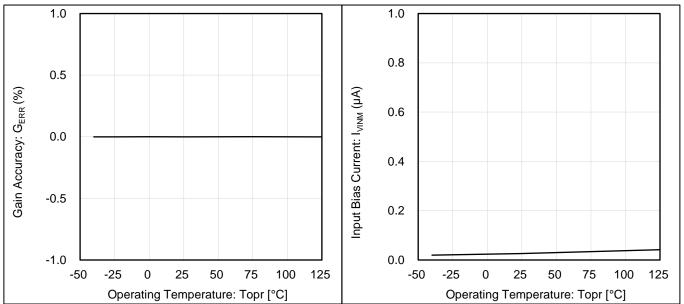


Figure 3. Gain Accuracy vs Operating Temperature

Figure 4. Input Bias Current vs Operating Temperature

Typical Performance Curves - continued

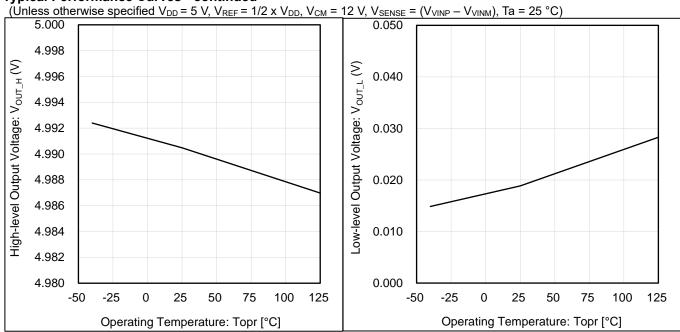


Figure 5. High-level Output Voltage vs Operating Temperature

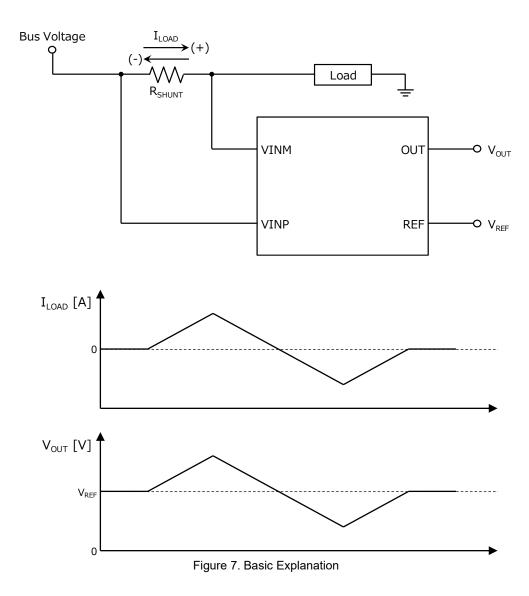
Figure 6. Low-level Output Voltage vs Operating Temperature

Basic Explanation

This IC has the structure specialized for Current Sense Amplifier and has the following features. Common mode voltage range is maximum 26 V with VDD of maximum 5.5 V, therefore it is possible to detect the current flowing in a power supply line exceeding VDD voltage. And its input bias current is very low.

This IC amplifies the voltage difference across the shunt resister between VINP and VINM and outputs a voltage with the REF pin as reference voltage.

If the current flows from VINP to VINM, OUT pin voltage is higher than REF pin voltage. If the current flows from VINM to VINP, OUT pin voltage is lower than REF pin voltage. When the voltages of VINP and VINM are equal, OUT pin voltage is equal to REF pin voltage.



 V_{OUT} is calculated by the below formula.

 $V_{OUT} = (R_{SHUNT} \times I_{LOAD} \times GAIN) + V_{REF}$

Where,

R_{SHUNT} is the Shunt resistance I_{LOAD} is the Load current GAIN is the Gain of Current Sense Amplifier V_{REF} is the REF pin voltage

Also, V_{OUT} needs to be GND < V_{OUT} < VDD.

Vout is clipped to Low-level Output Voltage (Vout_L) when it's under GND.

Vout is clipped to High-level Output Voltage (Vout_H) when it's over VDD.

Basic Explanation – continued

Input pin VINP and VINM needs to be connected to IC as close as possible in order to minimize the influence on series resistance of shunt resister.

For stability, dispose and connect a bypass capacitor for removing power source noise close to IC.

Selection of shunt resister

Shunt resister R_{SHUNT} should be selected considering the accuracy of measuring current and the maximum power dissipation according to an application.

If the value of shunt resister is high, it minimizes the influence of offset and increases the accuracy of measuring current. If the value of shunt resister is low, it reduces the power dissipation of VDD.

Shunt resister value is calculated by below formula.

$$R_{SHUNT} < (VDD - V_{REF}) / (abs(I_{LOADMAX}) \times GAIN)$$

Where

VDD is the Power Supply

abs(ILOADMAX) is the Maximum of load current (absolute value)

Control Sequence

- 1. Control Sequence
- 1.1 Power supply start-up sequence

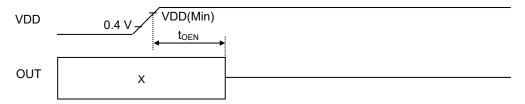


Figure 8. Timing Chart at Power ON

Stable time of OUT(toen) should be more than 1 ms.

1.2 Power supply end sequence

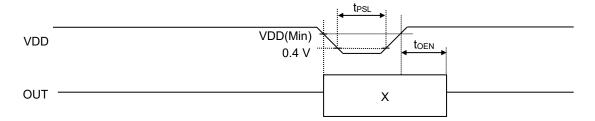


Figure 9. Timing Chart at Power OFF

Power off time(t_{PSL}) should be more than 1 ms.

If VDD voltage is under the recommended operating condition, LSI is unstable state. In that case, set Power OFF and ON again. When the power is ON again, the period of VDD<0.4 V should be more than t_{PSL}.

I/O Equivalence Circuits

I/O Equivalence Circu	IITS		
Pin Name	Equivalent Circuit Diagram	Pin Name	Equivalent Circuit Diagram
OUT	VDD	VINP VINM	
REF	VDD → W → W → W → W → W → W → W → W → W →		

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes - continued

10. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

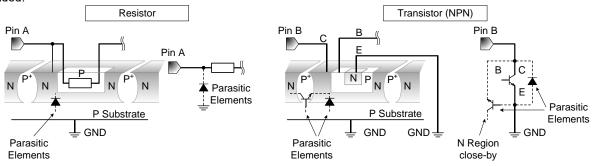
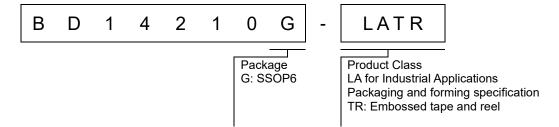


Figure 10. Example of Monolithic IC Structure

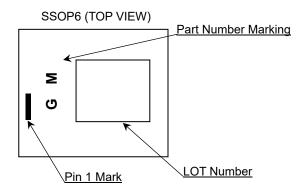
11. Ceramic Capacitor

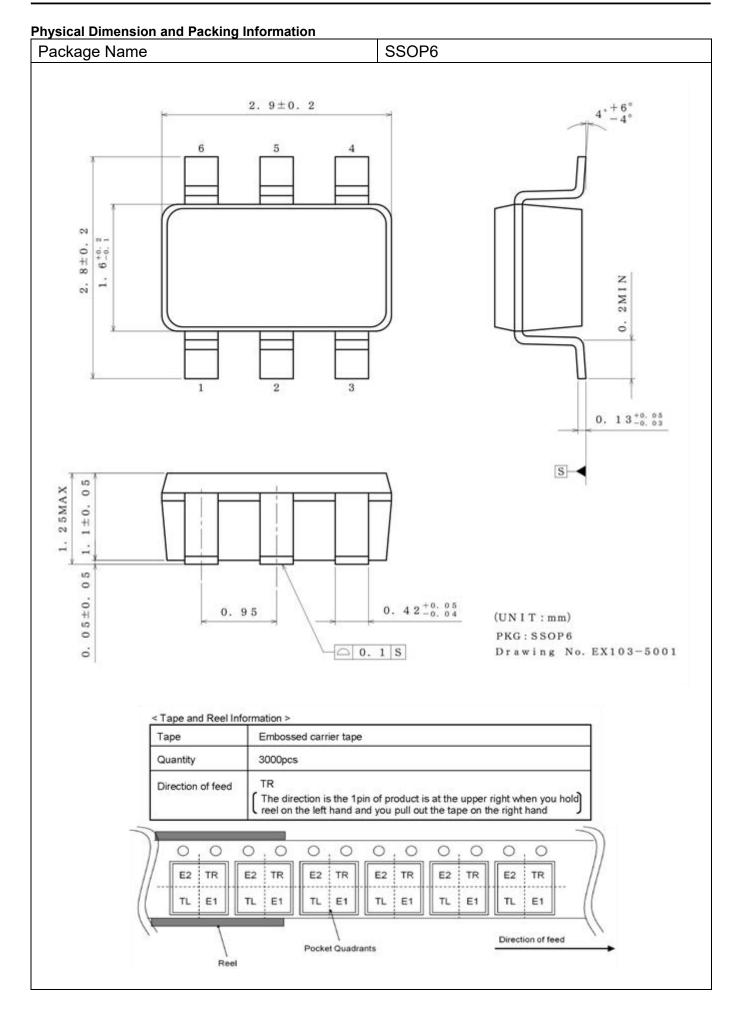
When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

Ordering Information



Marking Diagram





Revision History

Date	Revision	Changes
03.Mar.2022	001	New Release
28.Jun.2024	002	Revision up only

Notice

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JÁPAN	USA	EU	CHINA
CLASSIII	CL ACCIII	CLASS II b	CL ACCIII
CLASSIV	CLASSⅢ	CLASSIII	CLASSⅢ

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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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